## NSN 5961-00-403-2560

Semiconductor Device Set - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-403-2560 **Inclosure Material:** Plastic all transistor **Overall Length:** 0.250 inches all transistor **Terminal Length:** 0.400 inches all transistor **Overall Diameter:** 0.330 inches all transistor **Internal Configuration:** Junction contact all transistor **Internal Junction Configuration:** Pnp all transistor **Component Function Relationship:** Matched **Component Name And Quantity:** 2 transistor **Mounting Method:** Terminal all transistor **Terminal Circle Diameter:** 0.200 inches all transistor **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: -25.0 collector to base voltage/static/emitter open all transistor and -25.0 collector to emitter voltage/static/base open all transistor and -25.0 collector to emitter voltage, dc with base short-circuited to emitter all transistor and -4.0 emitter to base voltage, static, collector open all transistor **Power Rating Per Characteristic:** 700.0 milliwatts small-signal input power, common-collector absolute all transistor **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction all transistor **Special Features:** Fairchild semiconductor corp; texas instruments inc. Controlling agency; component part no. S2091 and swb1628 **Terminal Type And Quantity:** 3 uninsulated wire lead all transistor Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

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